

UNISONIC TECHNOLOGIES CO., LTD

03N50-CD

Preliminary

0.3A, 500V N-CHANNEL POWER MOSFET

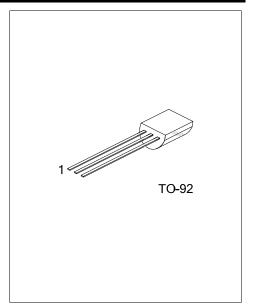
DESCRIPTION

The UTC **03N50-CD** is a high voltage power MOSFET and is designed to have better characteristics, such as fast switching time, low gate charge, low on-state resistance and have a high rugged avalanche characteristics. This power MOSFET is usually used at high speed switching applications in power supplies, PWM motor controls, high efficient DC to DC converters and bridge circuits.

FEATURES

- * $R_{DS(on)} \le 27 \ \Omega \ @ V_{GS}=10V, I_D=0.15A$
- * High breakdown voltage

ORDERING INFORMATION

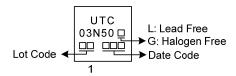


Ordering Number Lead Free Halogen Free		Daakaga	Pin Assignment			Deaking	
		Package	1	2	3	Packing	
03N50L-T92-B	03N50G-T92-B	TO-92	G	D	S	Tape Box	
03N50L-T92-K	03N50G-T92-K	TO-92	G	D	S	Bulk	
Noto: Dia Assignment: C: Cato D: Drain C: Source							

Note:	Pin Assignment: G: Gate	D: Drain	S: Source	

03N50 <u>G-T92-B</u>	
(1)Packing Type	(1) B: Tape Box, K: Bulk
(2)Package Type	(2) T92: TO-92
(3)Green Package	(3) G: Halogen Free and Lead Free, L: Lead Free

MARKING



■ ABSOLUTE MAXIMUM RATINGS (T_A =25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V _{DSS}	500	V
Gate-Source Voltage		V _{GSS}	±30	V
	Continuous	I _D	0.3	А
Drain Current	Pulsed	I _{DM}	0.6	А
Power Dissipation		P _D	425	mW
Junction Temperature		TJ	+150	°C
Storage Temperature Range		T _{STG}	-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating : Pulse width limited by maximum junction temperature.

THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT	
Junction to Ambient	θ _{JA}	416	°C/W	
Junction to Case	θ _{JC}	294	°C/W	

Note: Device mounted on FR-4 substrate P_{C} board, 2oz copper, with 1inch square copper plate.

■ ELECTRICAL CHARACTERISTICS (T_A =25°C, unless otherwise specified)

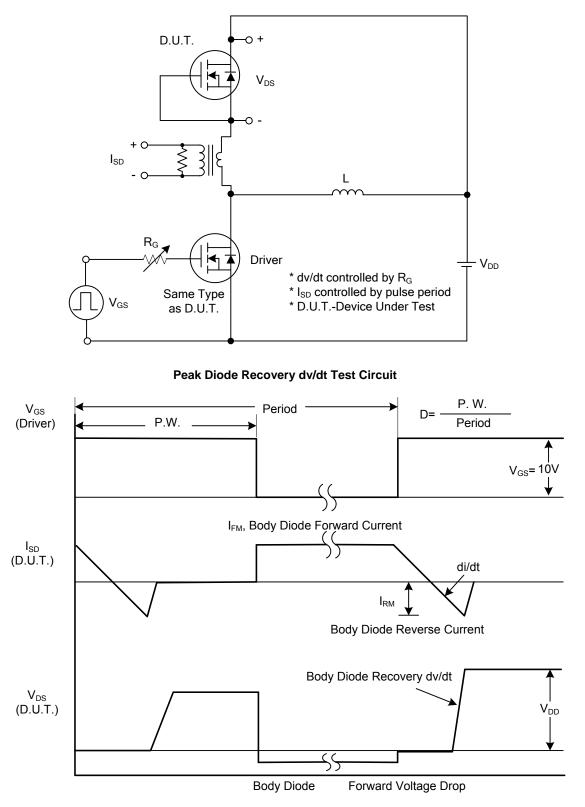
PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage		BV _{DSS}	I _D =250μΑ, V _{GS} =0V	500			V
Drain-Source Leakage Current		I _{DSS}	V _{DS} =500V, V _{GS} =0V, T _A =25°C			10	μA
	Forward	I _{GSS}	V _{GS} =+30V, V _{DS} =0V			+100	nA
Gate-Source Leakage Current	Reverse		V _{GS} =-30V, V _{DS} =0V			-100	nA
ON CHARACTERISTICS							
Gate Threshold Voltage		V _{GS(TH)}	V _{DS} =V _{GS} , Ι _D =250μΑ	2.0		4.0	V
Static Drain-Source On-State Res	sistance	R _{DS(ON)}	V _{GS} =10V, I _D =0.15A			27	Ω
DYNAMIC PARAMETERS							
Input Capacitance		C _{ISS}			30		рF
Output Capacitance		Coss	V _{GS} =0V, V _{DS} =25V, f=1.0MHz		3.5		рF
Reverse Transfer Capacitance		C _{RSS}			0.2		рF
SWITCHING PARAMETERS							
Total Gate Charge		Q_{G}			7		nC
Gate to Source Charge		Q _{GS}	V_{DS} =400V, V_{GS} =10V, I_{D} =0.3A,		3		nC
Gate to Drain Charge		Q_{GD}	I _D =100μΑ (Note1,2)		0.8		nC
Turn-ON Delay Time		t _{D(ON)}			6		ns
Rise Time		t _R	V _{DS} =100V, V _{GS} =10V, I _D =0.3A,		16		ns
Turn-OFF Delay Time Fall-Time		t _{D(OFF)}	R _G =25Ω (Note1,2)		20		ns
		t⊨			105		ns
SOURCE- DRAIN DIODE RATIN	IGS AND CI	HARACTERI	STICS				
Maximum Body-Diode Continuou	s Current	ls				0.3	Α
Maximum Body-Diode Pulsed Current		I _{SM}				0.6	Α
Drain-Source Diode Forward Voltage		V _{SD}	I _S =0.3A, V _{GS} =0V			1.4	V
Reverse Recovery Time		t _{rr}			72		ns
Reverse Recovery Charge		Q _{rr}	V _{GS} =0V, I _S =0.3A, di/dt=100A/µs		160		nC
Notos: 1 Bulso Tost: Bulso Width		ity Cyclos 20	L				

Notes: 1. Pulse Test: Pulse Width≤300µs, Duty Cycle≤2%

2. Essentially independent of operating temperature.



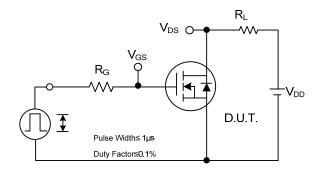
TEST CIRCUITS AND WAVEFORMS

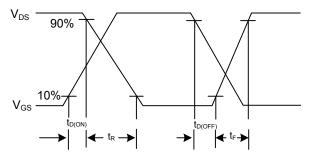




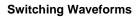


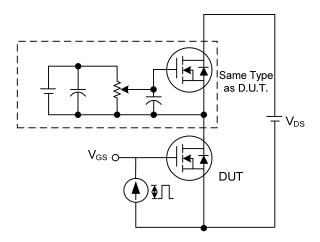
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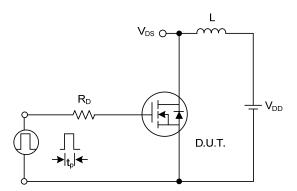




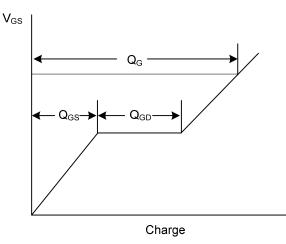




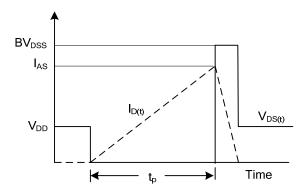
Gate Charge Test Circuit



Unclamped Inductive Switching Test Circuit







Unclamped Inductive Switching Waveforms



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